

LIST OF REFERENCES CITED BY APPLICANT (Use several sheets if necessary)	ATTY DOCKET NO. 060889-5002	APPLICATION NO. <u>10800221</u> To Be Assigned
	APPLICANT McElheny and Liu	
	FILING DATE Herewith	GROUP To Be Assigned

U.S. PATENT DOCUMENTS


*EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS	FILING DATE IF APPROPRIATE
WL	3,719,866	03-1973	Naber et al.	257	326	
WL	4,935,802	06-1990	Noguchi et al.	257	314	
WL	5,108,939	04-1992	Manley et al.	438	594	
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WL	6,303,521	10-2001	Jenq	438	770	
WL	6,462,388	10-2002	Perner	257	390	

FOREIGN PATENT DOCUMENTS

DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS	TRANSLATION
					YES NO

OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, Etc.)

WL	Fung, S., Chan, M., Ko, P., "Inverse-Narrow-Width Effect of Deep Sub-Micrometer Mosfets with Locos Isolation," Received 10/08/1996, Revised 03/17/1997, Solid State Electronics, Vol. 41, No. 12, pp. 1885-1889, 1997
WL	Wayne Wolf, "Modern VLSI Design, A System Approach," PTR Prentice Hall, Englewood Cliffs, New Jersey 07632, p. 29
WL	Imamiya et al., "MP 6.6, A 130mm ² 256Mb NAND Flash with Shallow Trench Isolation Technology," 1999 IEEE International Solid-State Circuits Conference, 0-7803-5129/99, IEEE 1999

EXAMINER 	DATE CONSIDERED <u>9/14/2004</u>
*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	